

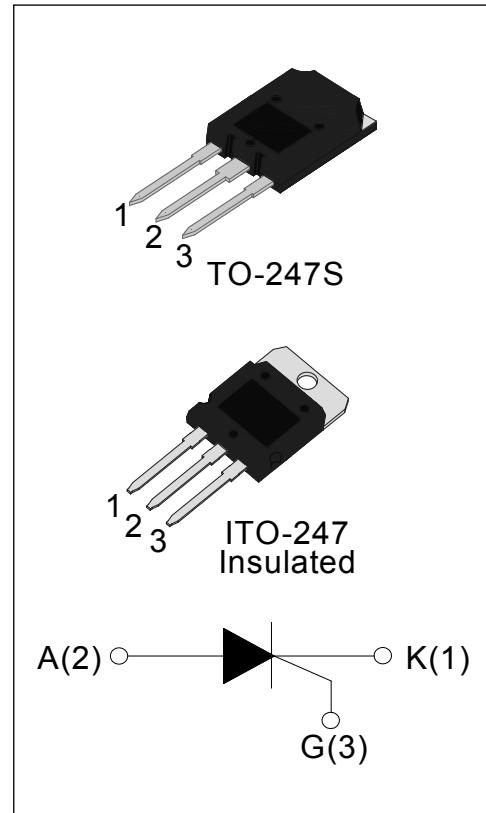
KJS1690

DESCRIPTION:

With high ability to withstand the shock loading of large current, KJS1690 Series provide high dv/dt rate with high frequency noise immunity. Products are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. From all three pins to external heatsink, KJS1690IS provides an insulation voltage of 2500 V_{RMS}, complying with UL standards.

MAIN FEATURES

| Symbol | Value | Unit |
|------------------------------------|-------|------|
| I _{T(RMS)} | 90 | A |
| V _{DRM} /V _{RRM} | 1600 | V |
| I _{GT} | ≤80 | mA |



ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Value | Unit |
|---|---------------------|-----------------------|------------------|
| Storage junction temperature range | T _{stg} | -40-150 | °C |
| Operating junction temperature range | T _j | -40-125 | °C |
| Repetitive peak off-state voltage(T _j =25°C) | V _{DRM} | 1600 | V |
| Repetitive peak reverse voltage(T _j =25°C) | V _{RRM} | 1600 | V |
| Non repetitive surge peak Off-state voltage | V _{DSM} | V _{DRM} +100 | V |
| Non repetitive peak reverse voltage | V _{RSM} | V _{RRM} +100 | V |
| RMS on-state current (T _c =80°C) | I _{T(RMS)} | 90 | A |
| Non repetitive surge peak on-state current (tp=10ms) | I _{TSM} | 1000 | A |
| I ² t value for fusing (tp=10ms) | I ² t | 2000 | A ² s |

KJS1690

| | | | |
|--|-------------|-----|------------|
| Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$) | di/dt | 150 | A/ μ s |
| Peak gate current | I_{GM} | 4 | A |
| Average gate power dissipation | $P_{G(AV)}$ | 1 | W |
| Peak gate power | P_{GM} | 5 | W |

ELECTRICAL CHARACTERISTICS ($T_j=25^\circ C$ unless otherwise specified)

| Symbol | Test Condition | Value | | | Unit |
|----------|--|-------|------|------|------------|
| | | MIN. | TYP. | MAX. | |
| I_{GT} | $V_D=12V R_L=33\Omega$ | - | - | 80 | mA |
| V_{GT} | | - | - | 1.5 | V |
| V_{GD} | $V_D=V_{DRM} T_j=125^\circ C R_L=3.3K\Omega$ | 0.25 | - | - | V |
| I_L | $I_G=1.2I_{GT}$ | - | - | 250 | mA |
| I_H | $I_T=1A$ | - | - | 150 | mA |
| dV/dt | $V_D=2/3V_{DRM}$ Gate Open $T_j=125^\circ C$ | 1000 | - | - | V/ μ s |

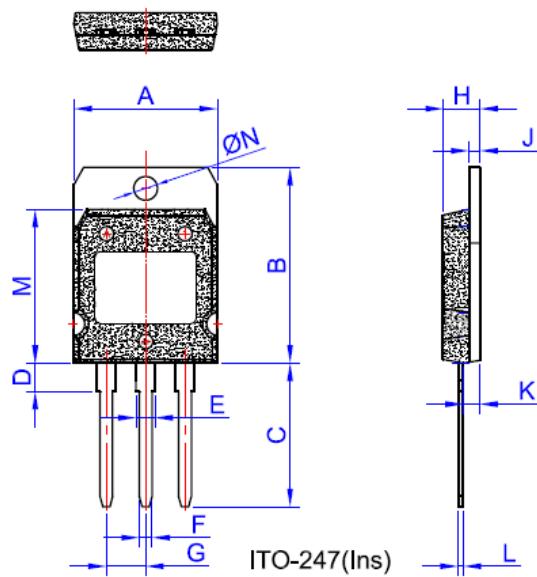
STATIC CHARACTERISTICS

| Symbol | Parameter | | Value(MAX) | Unit |
|-----------|---------------|-------------------|------------|---------|
| V_{TM} | $I_{TM}=110A$ | $t_p=380\mu s$ | 1.8 | V |
| I_{DRM} | $V_D=V_{DRM}$ | $T_j=25^\circ C$ | 50 | μA |
| I_{RRM} | | $T_j=125^\circ C$ | 10 | mA |

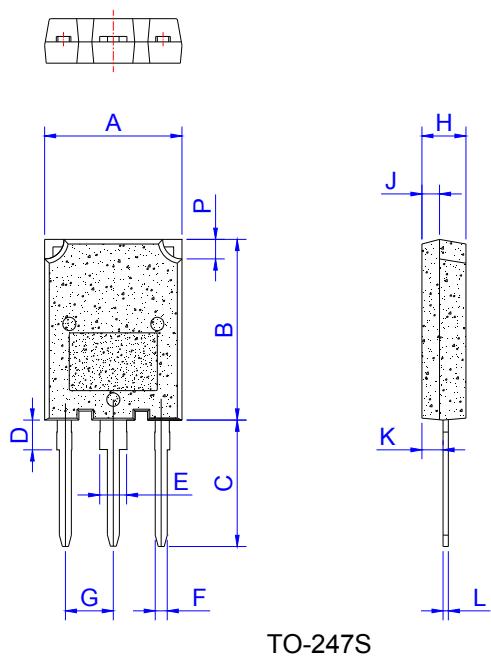
THERMAL RESISTANCES

| Symbol | Parameter | Value | Unit |
|---------------|----------------------|--------------------------|------|
| $R_{th(j-c)}$ | junction to case(AC) | TO-247S/ ITO-247(Ins) | 0.43 |

PACKAGE MECHANICAL DATA



| Ref | Dimensions | | | | | |
|-----|-------------|------|------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 19.7 | 19.9 | 20.1 | 0.776 | 0.783 | 0.791 |
| B | 26.9 | 27.1 | 27.3 | 1.059 | 1.067 | 1.075 |
| C | 19.4 | 19.9 | 20.4 | 0.764 | 0.783 | 0.803 |
| D | 3.8 | 3.9 | 4.0 | 0.15 | 0.154 | 0.157 |
| E | 2.56 | 2.66 | 2.76 | 0.101 | 0.105 | 0.109 |
| F | 1.66 | 1.76 | 1.86 | 0.065 | 0.069 | 0.073 |
| G | | 5.45 | | | 0.215 | |
| H | 5.05 | 5.10 | 5.5 | 0.199 | 0.201 | 0.217 |
| J | 1.45 | 1.50 | 1.55 | 0.057 | 0.059 | 0.061 |
| K | 2.20 | 2.30 | 2.40 | 0.087 | 0.091 | 0.094 |
| L | 0.60 | 0.70 | 0.80 | 0.024 | 0.028 | 0.031 |
| M | 21.2 | 21.3 | 21.4 | 0.835 | 0.839 | 0.843 |
| ØN | 3.20 | 3.30 | 3.40 | 0.126 | 0.130 | 0.134 |



| Ref. | Dimensions | | | | | |
|------|-------------|------|------|--------|------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 15.1 | | 16.1 | 0.594 | | 0.634 |
| B | 19.8 | | 20.8 | 0.78 | | 0.819 |
| C | 13.8 | | 14.8 | 0.543 | | 0.583 |
| D | 3.00 | | 4.00 | 0.118 | | 0.157 |
| E | 2.75 | | 3.35 | 0.108 | | 0.132 |
| F | 1.30 | | 1.50 | 0.051 | | 0.059 |
| G | 5.10 | | 5.80 | 0.201 | | 0.228 |
| H | 4.50 | | 5.50 | 0.177 | | 0.217 |
| J | 1.45 | | 2.15 | 0.057 | | 0.085 |
| K | 1.90 | | 2.80 | 0.075 | | 0.110 |
| L | 0.55 | | 0.80 | 0.022 | | 0.031 |
| P | 2.00 | | 2.40 | 0.079 | | 0.094 |

FIG.1: Maximum power dissipation versus RMS on-state current

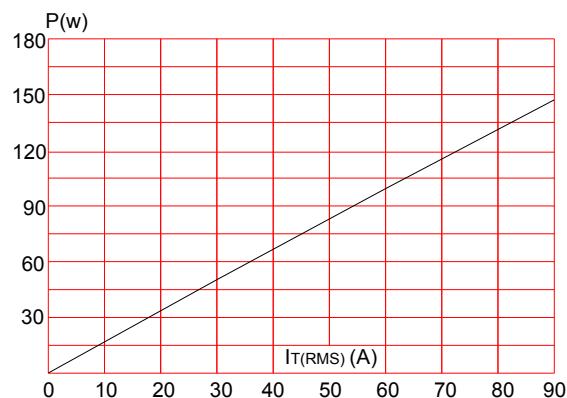


FIG.3: Surge peak on-state current versus number of cycles

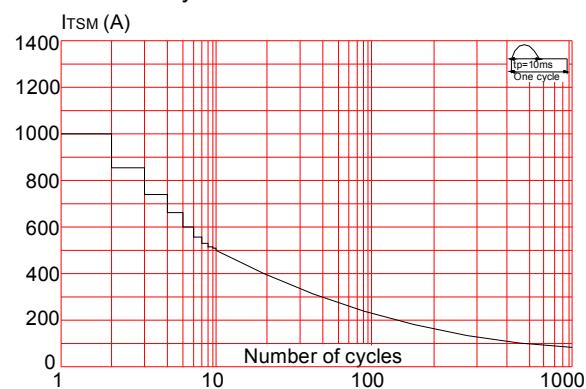


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of $\frac{dI}{dt}$ ($\text{dI/dt} < 150\text{A}/\mu\text{s}$)

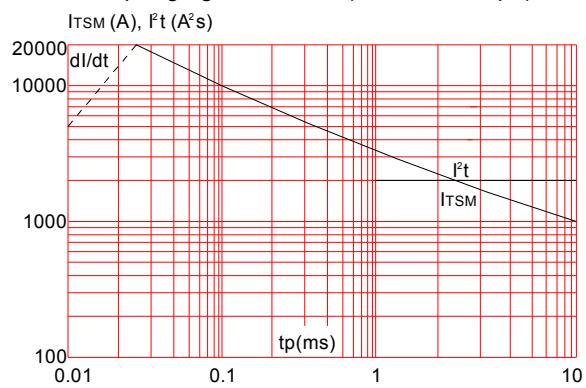


FIG.2: RMS on-state current versus case temperature

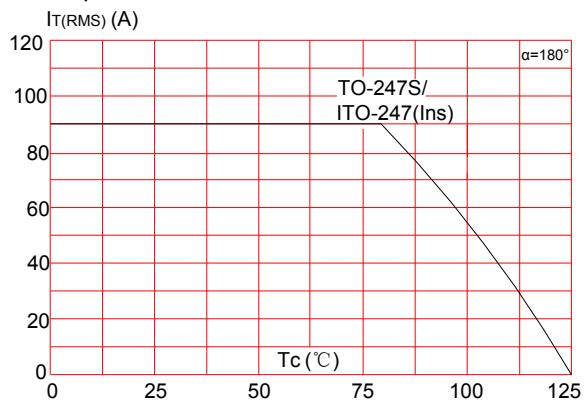


FIG.4: On-state characteristics (maximum values)

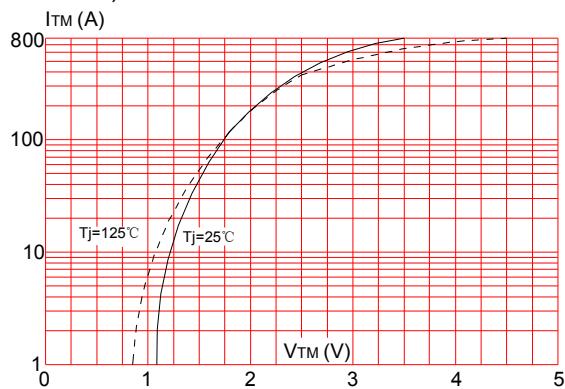


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

